

SN74LVC1G06 Single Inverter Buffer or Driver With Open-Drain Output

1 Features

- ESD protection exceeds JESD 22
 - 2000V human body model (A114-A)
 - 200V machine model (A115-A)
 - 1000V charged-device model (C101)
- Available in the Texas Instruments NanoFree™ package
- Supports 5V V_{CC} operation
- Input and open-drain output accept voltages up to 5.5V
- Maximum t_{pd} of 4.5ns at 3.3V at 125°C
- Low power consumption, 10 μ A maximum I_{CC}
- ± 24 mA output drive at 3.3V for open-drain devices
- I_{off} supports partial-power-down mode and back-drive protection
- Latch-up performance exceeds 100mA per JESD 78, class II
- Can be used for up or down translation
- Schmitt trigger action on all ports

2 Applications

- AV receivers
- Blu-ray players and home theaters
- DVD recorders and players
- Desktop or notebook PCs
- Digital radio or internet radio players
- Digital video cameras (DVC)
- Embedded PCs
- GPS: personal navigation devices
- Mobile internet devices
- Network projector front-ends
- Portable media players
- Pro audio mixers
- Smoke detectors
- Solid state drive (SSD): enterprise
- High-definition (HDTV)
- Tablets: enterprise
- Audio docks: portable
- DLP front projection systems
- DVR and DVS
- Digital picture frame (DPF)
- Digital still cameras

3 Description

This single inverter buffer and driver is designed for 1.65V to 5.5V V_{CC} operation.

NanoFree package technology is a major breakthrough in IC packaging concepts, using the die as the package.

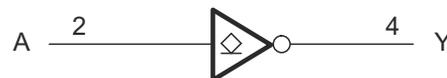
The output of the SN74LVC1G06 device is open-drain and can be connected to other open-drain outputs to implement active-low wired-OR or active-high wired-AND functions. The maximum sink current is 32mA.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs when the device is powered down. This inhibits current backflow into the device which prevents damage to the device.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾	BODY SIZE (NOM) ⁽³⁾
SN74LVC1G06	DBV (SOT-23, 5)	2.90mm × 2.80mm	2.90mm × 1.60mm
	DCK (SC70, 5)	2.00mm × 2.10mm	2.00mm × 1.25mm
	DRL (SOT-5X3, 5)	1.60mm × 1.60mm	1.60mm × 1.20mm
	DRY (USON, 6)	1.45mm × 1.00mm	1.45mm × 1.00mm
	DSF (X2SON, 6)	1.00mm × 1.00mm	1.00mm × 1.00mm
	YZP (DSBGA, 5)	1.75mm × 1.25mm	1.40mm × 0.90mm
	YZV (DSBGA, 4)	1.25mm × 1.25mm	0.90mm × 0.90mm
	DPW (X2SON, 5)	0.80mm × 0.80mm	0.80mm × 0.80mm

- (1) For more information, see [Mechanical, Packaging, and Orderable Information](#).
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.
- (3) The body size (length × width) is a nominal value and does not include pins.



Logic Diagram (Positive Logic)



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4 Pin Configuration and Functions

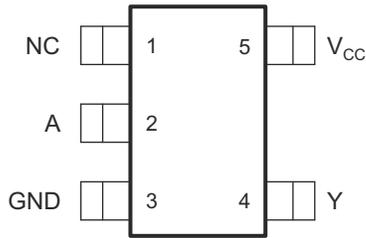


Figure 4-1. DBV Package 5-Pin SOT-23 Top View

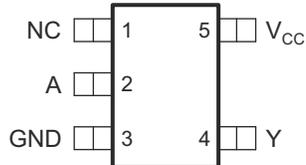


Figure 4-3. DCK Package 5-Pin SC70 Top View

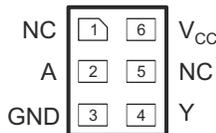


Figure 4-5. DRY Package 6-Pin SON Top View



Figure 4-7. YZP Package 5-Pin DSBGA Top View

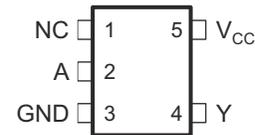


Figure 4-2. DRL Package 5-Pin SOT-5X3 Top View



Figure 4-4. DPW Package 5-Pin X2SON Top View

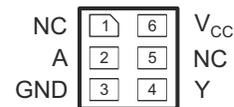


Figure 4-6. DSF Package 6-Pin SON Top View



Figure 4-8. YZV Package 4-Pin DSBGA Top View

Table 4-1. Pin Functions (2)

NAME	PIN				I/O	DESCRIPTION
	DBV, DCK, DRL, DPW	DRY, DSF	YZP	YZV		
A	2	2	B1	A1	I	Input
DNU	—	—	A1	—	—	Do not use
GND	3	3	C1	B1	—	Ground
NC ⁽¹⁾	1	1 5	—	—	—	Not connected
V _{CC}	5	6	A2	A2	—	Power pin
Y	4	4	C2	B2	O	Output

(1) NC – No internal connection

(2) See mechanical drawings for dimensions.

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage	-0.5	6.5	V
V _I	Input voltage ⁽²⁾	-0.5	6.5	V
V _O	Voltage applied to any output in the high-impedance or power-off state ⁽²⁾	-0.5	6.5	V
V _O	Voltage applied to any output in the high or low state ^{(2) (3)}	-0.5	6.5	V
I _{IK}	Input clamp current	V _I < 0	-50	mA
I _{OK}	Output clamp current	V _O < 0	-50	mA
I _O	Continuous output current		±50	mA
	Continuous current through V _{CC} or GND		±100	mA
T _J	Junction temperature	-65	150	°C
T _{stg}	Storage temperature	-65	150	°C

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V_{CC} is provided in the *Recommended Operating Conditions* table.

5.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	2000
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	1000
		Machine Model (MM), per A115-A	200

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT	
V _{CC}	Supply voltage	Operating	1.65	5.5	V
		Data retention only	1.5		
V _{IH}	High-level input voltage	V _{CC} = 1.65V to 1.95V	0.65 × V _{CC}		V
		V _{CC} = 2.3V to 2.7V	1.7		
		V _{CC} = 3V to 3.6V	2		
		V _{CC} = 4.5V to 5.5V	0.7 × V _{CC}		
V _{IL}	Low-level input voltage	V _{CC} = 1.65V to 1.95V	0.35 × V _{CC}		V
		V _{CC} = 2.3V to 2.7V	0.7		
		V _{CC} = 3V to 3.6V	0.8		
		V _{CC} = 4.5V to 5.5V	0.3 × V _{CC}		
V _I	Input voltage	0	5.5	V	
V _O	Output voltage	0	5.5	V	
I _{OL}	Low-level output current	V _{CC} = 1.65V	4		mA
		V _{CC} = 2.3V	8		
		V _{CC} = 3V	16		
			24		
		V _{CC} = 4.5V	32		
Δt/Δv	Input transition rise or fall rate	V _{CC} = 1.8V ± 0.15V, 2.5V ± 0.2V	20		ns/V
		V _{CC} = 3.3V ± 0.3V	10		
		V _{CC} = 5V ± 0.5V	5		
T _A	Operating free-air temperature	–40	125	°C	

(1) All unused inputs of the device must be held at V_{CC} or GND to establish proper device operation. See [Implications of Slow or Floating CMOS Inputs application report](#).

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾	SN74LVC1G06							UNIT	
	DBV (SOT-23)	DCK (SC70)	DRL (SOT-5X3)	DRY (SON)	DPW (X2SON)	YZV (DSBGA)	YZP (DSBGA)		
	5 PINS	5 PINS	5 PINS	5 PINS	5 PINS	4 PINS	5 PINS		
R _{θJA}	Junction-to-ambient thermal resistance	357.1	371.0	296.2	369.6	511	168.2	144.4	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	263.7	297.5	137.3	257.6	241.9	2.1	1.3	°C/W
R _{θJB}	Junction-to-board thermal resistance	264.4	258.6	145.3	230.8	374.2	55.9	39.9	°C/W
ψ _{JT}	Junction-to-top characterization parameter	195.6	195.6	14.7	77.2	45	1.1	0.5	°C/W
ψ _{JB}	Junction-to-board characterization parameter	262.2	256.2	145.9	231	373.3	56.3	39.7	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	168	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

5.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		V _{CC}	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{OL}	High-level output voltage	I _{OL} = 100μA	1.65V to 5.5V			0.1	V
		I _{OL} = 4mA	1.65V			0.45	
		I _{OL} = 8mA	2.3V			0.3	
		I _{OL} = 16mA	3V			0.4	
		I _{OL} = 24mA				0.55	
		I _{OL} = 32mA	4.5V			0.55	
I _I	Inflection-point current	V _I = 5.5V or GND	A input	0 to 5.5V		±1	μA
I _{off}	Off-state current	V _I or V _O = 5.5V		0		±10	μA
I _{CC}		V _I = 5.5V or GND, I _O = 0		1.65V to 5.5V		10	μA
ΔI _{CC}		One input at V _{CC} – 0.6V, other inputs at V _{CC} or GND		3V to 5.5V		500	μA
C _I	Input capacitance	V _I = V _{CC} or GND		3.3V		4	pF
C _O	Off-state capacitance	V _O = V _{CC} or GND		3.3V		5	pF

(1) All typical values are at V_{CC} = 3.3V, T_A = 25°C.

5.6 Switching Characteristics: –40°C to +85°C

over recommended operating free-air temperature range, T_A = –40°C to +85°C (unless otherwise noted) (see [Figure 6-1](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC}	MIN	MAX	UNIT	
t _{pd}	Propagation delay	A	Y	1.8V ± 0.15V	2.2	6.5	ns
				2.5V ± 0.2V	1.1	4	
				3.3V ± 0.3V	1.2	4	
				5V ± 0.5V	1	3	

5.7 Switching Characteristics: –40°C to +125°C

over recommended operating free-air temperature range, T_A = –40°C to +125°C (unless otherwise noted) (see [Figure 6-1](#))

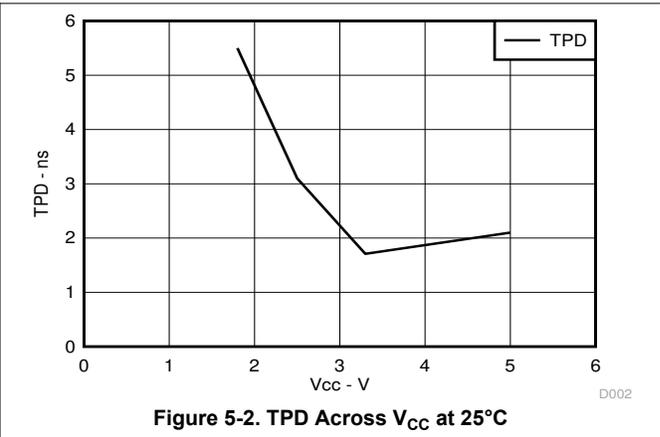
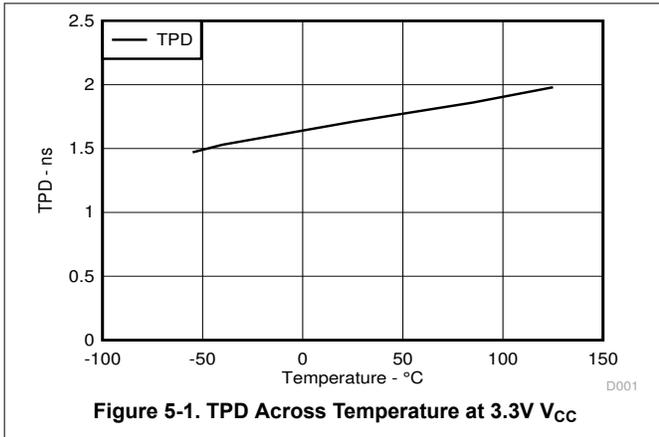
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC}	MIN	MAX	UNIT	
t _{pd}	Propagation delay	A	Y	1.8V ± 0.15V	2.2	7	ns
				2.5V ± 0.2V	1.1	4.5	
				3.3V ± 0.3V	1.2	4.5	
				5V ± 0.5V	1	3.5	

5.8 Operating Characteristics

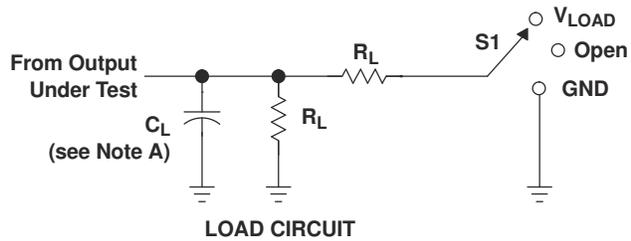
T_A = 25°C

PARAMETER	TEST CONDITIONS	V _{CC}	TYP	UNIT	
C _{pd}	Power dissipation capacitance	f = 10MHz	1.8V	3	pF
			2.5V	3	
			3.3V	4	
			5V	6	

5.9 Typical Characteristics

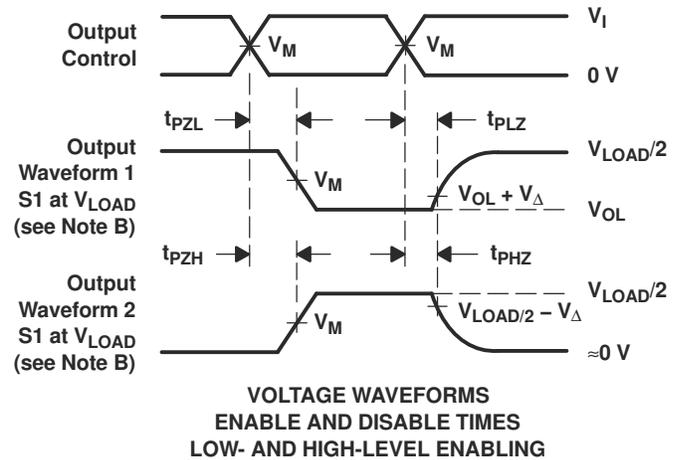
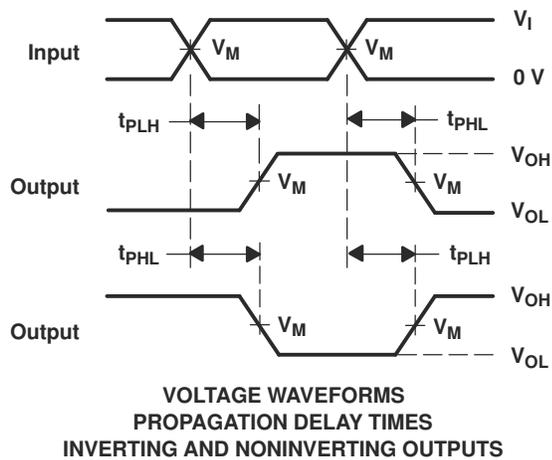
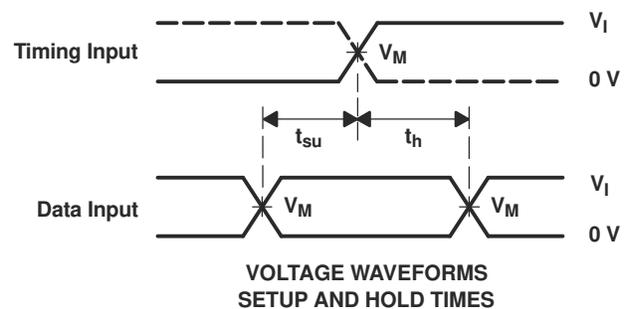
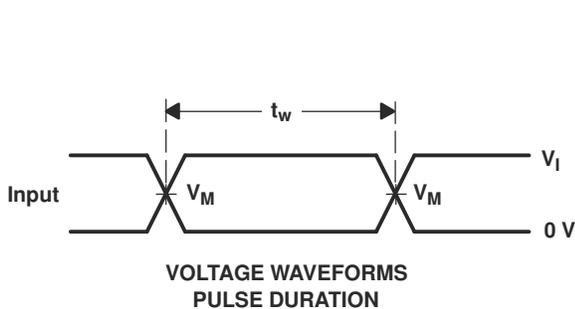


Parameter Measurement Information



TEST	S1
t_{pZL} (see Notes E and F)	V_{LOAD}
t_{pLZ} (see Notes E and G)	V_{LOAD}
t_{pHZ}/t_{pZH}	V_{LOAD}

V_{CC}	INPUT		V_M	V_{LOAD}	C_L	R_L	V_{Δ}
	V_I	t_r/t_f					
$1.8\text{ V} \pm 0.15\text{ V}$	V_{CC}	$\leq 2\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	30 pF	1 k Ω	0.15 V
$2.5\text{ V} \pm 0.2\text{ V}$	V_{CC}	$\leq 2\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V
$3.3\text{ V} \pm 0.3\text{ V}$	3 V	$\leq 2.5\text{ ns}$	1.5 V	6 V	50 pF	500 Ω	0.3 V
$5\text{ V} \pm 0.5\text{ V}$	V_{CC}	$\leq 2.5\text{ ns}$	$V_{CC}/2$	$2 \times V_{CC}$	50 pF	500 Ω	0.3 V



- NOTES:
- A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10\text{ MHz}$, $Z_O = 50\ \Omega$.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. Since this device has open-drain outputs, t_{pLZ} and t_{pZL} are the same as t_{pd} .
 - F. t_{pZL} is measured at V_M .
 - G. t_{pLZ} is measured at $V_{OL} + V_{\Delta}$.
 - H. All parameters and waveforms are not applicable to all devices.

Figure 6-1. Load Circuit and Voltage Waveforms (Open Drain)

6 Detailed Description

6.1 Overview

The SN74LVC1G06 device contains one open-drain inverter with a maximum sink current of 32mA. This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs when the device is powered down. This inhibits current backflow into the device which prevents damage to the device.

6.2 Functional Block Diagram

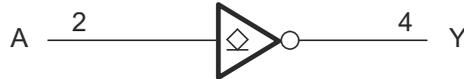


Figure 6-1. Logic Diagram (Positive Logic)

6.3 Feature Description

6.3.1 CMOS Open-Drain Outputs

The open-drain output allows the device to sink current to GND but not to source current from V_{CC} . When the output is not actively pulling the line low, it will go into a high impedance state (tri-state). This allows the device to be used for a wide variety of applications, including up-translation and down-translation, as the output voltage can be determined by an external pullup.

Consider the drive capability of this device creates fast edges into light loads so routing and load conditions prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important for the power output of the device to be limited to avoid thermal runaway and damage due to over-current. The electrical and thermal limits defined in the [Absolute Maximum Ratings](#) must be followed at all times.

6.3.2 Standard CMOS Inputs

The impedance for standard CMOS inputs is high. Typically, a CMOS input is modeled as a resistor in parallel with the input capacitance as shown in the [Electrical Characteristics](#). The worst case resistance is calculated with the maximum input voltage, given in the [Absolute Maximum Ratings](#), and the maximum input leakage current, given in the [Electrical Characteristics](#), using ohm's law ($R = V \div I$).

Signals applied to the inputs need to have fast edge rates, as defined by $\Delta t/\Delta v$ in the [Recommended Operating Conditions](#) to avoid excessive current consumption and oscillations. If a slow or noisy input signal is required, a device with a Schmitt-trigger input should be used to condition the input signal before the standard CMOS input.

6.3.3 Negative Clamping Diodes

The inputs and outputs to this device have negative clamping diodes as depicted in Figure 6-2.

CAUTION

Voltages beyond the values specified in the [Absolute Maximum Ratings](#) table can cause damage to the device. The input negative-voltage and the output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

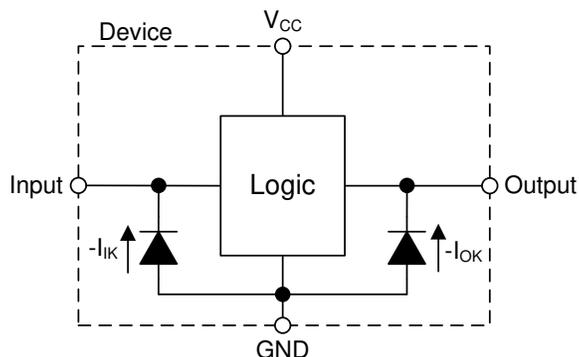


Figure 6-2. Electrical Placement of Clamping Diodes for Each Input and Output

6.3.4 Partial Power Down (I_{off})

Each input and output enter a high impedance state when the supply voltage is 0V. The maximum leakage into or out of any input or output pin on the device is specified by I_{off} in the [Electrical Characteristics](#).

6.3.5 Over-voltage Tolerant Inputs

Input signals to this device can be driven above the supply voltage as long as the input signals remain below the maximum input voltage value specified in the [Recommended Operating Conditions](#).

6.4 Device Functional Modes

Table 6-1 lists the functional modes of the SN74LVC1G06.

Table 6-1. Function Table

INPUT A	OUTPUT Y
L	Hi-Z
H	L

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

The SN74LVC1G06 is a high-drive CMOS device that can be used to implement a high output drive buffer, such as an LED application. It can sink 32mA of current at 4.5V making it appropriate for high-drive applications. It is good for high-speed applications up to 100MHz. The inputs are 5.5V tolerant allowing it to translate up or down to V_{CC} . Below shows a simple LED driver application for a single channel of the device.

7.2 Typical Application

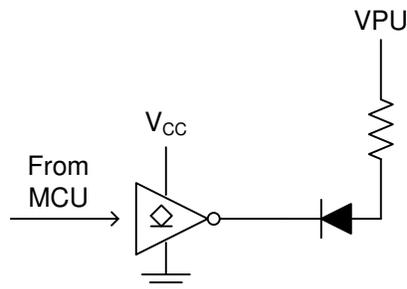


Figure 7-1. Typical Application Diagram

7.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

7.2.2 Detailed Design Procedure

- Recommended Input Conditions
 - Rise time and fall time specs. See $(\Delta t/\Delta V)$ in the [Recommended Operating Conditions](#) table.
 - Specified high and low levels. See $(V_{IH}$ and $V_{IL})$ in the [Recommended Operating Conditions](#) table.
 - Inputs are overvoltage tolerant allowing them to go as high as $(V_I \text{ max})$ in the [Recommended Operating Conditions](#) table at any valid V_{CC} .
- Recommended Output Conditions
 - Load currents should not exceed $(I_O \text{ max})$ per output and should not exceed (Continuous current through V_{CC} or GND) total current for the part. These limits are located in the [Absolute Maximum Ratings](#) table.
 - Outputs should not be pulled above 5.5V.

7.2.3 Application Curve

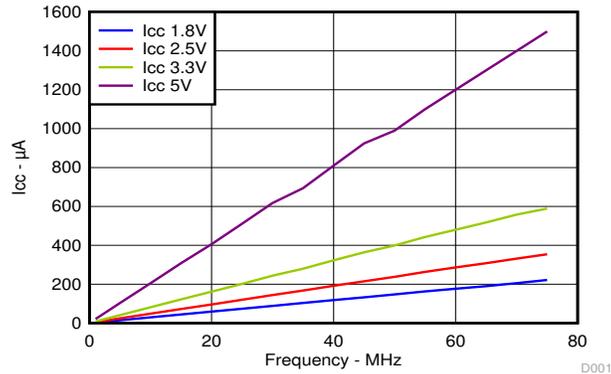


Figure 7-2. I_{CC} vs Frequency

7.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the [Recommended Operating Conditions](#) table.

The V_{CC} pin must have a good bypass capacitor to prevent power disturbance. A 0.1µF capacitor is recommended, and it is acceptable to parallel multiple bypass caps to reject different frequencies of noise. 0.1µF and 1µF capacitors are commonly used in parallel. For the best results, install the bypass capacitor as close to the power pin as possible.

7.4 Layout

7.4.1 Layout Guidelines

Even low data rate digital signals can contain high-frequency signal components due to fast edge rates. When a printed-circuit board (PCB) trace turns a corner at a 90° angle, a reflection can occur. A reflection occurs primarily because of the change of width of the trace. At the apex of the turn, the trace width increases to 1.414 times the width. This increase upsets the transmission-line characteristics, especially the distributed capacitance and self-inductance of the trace which results in the reflection. Not all PCB traces can be straight and therefore some traces must turn corners. [Figure 7-3](#) shows progressively better techniques of rounding corners. Only the last example (BEST) maintains constant trace width and minimizes reflections.

An example layout is given in [Figure 7-4](#) for the DPW (X2SON-5) package. This example layout includes a 0402 (metric) capacitor and uses the measurements found in the example board layout appended to this end of this data sheet. A via of diameter 0.1mm (3.973mil) is placed directly in the center of the device. This via can be used to trace out the center pin connection through another board layer, or it can be left out of the layout.

7.4.2 Layout Example

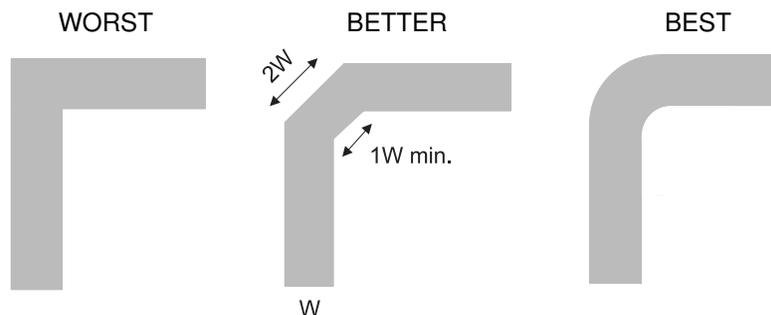


Figure 7-3. Trace Example

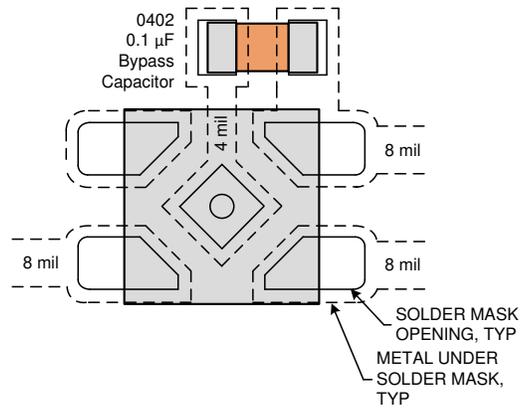


Figure 7-4. Example Layout With DPW (X2SON-5) Package

8 Device and Documentation Support

8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.2 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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8.3 Trademarks

NanoFree™ and TI E2E™ are trademarks of Texas Instruments.

All trademarks are the property of their respective owners.

8.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.5 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision AA (June 2025) to Revision AB (October 2025)	Page
• Changed Junction-to-ambient thermal resistance value for DCK package from: 276.1°C/W to: 371.10C/W ...	5
• Changed Junction-to-case (top) thermal resistance value for DCK package from: 178.9°C/W to: 297.5°C/W .	5
• Changed Junction-to-board thermal resistance value for DCK package from: 70.9°C/W to: 258.2°C/W	5
• Changed Junction-to-top characterization value for DCK package from: 47°C/W to: 195.6°C/W	5
• Changed Junction-to-board characterization value for DCK package from: 69.3°C/W to: 256.2°C/W	5

Changes from Revision Z (November 2017) to Revision AA (June 2025)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
• Changed <i>Device Information</i> table to <i>Package Information</i>	1
• Changed Junction-to-ambient thermal resistance value for DBV package from: 231.5°C/W to: 357.1°C/W	5
• Changed Junction-to-case (top) thermal resistance value for DBV package from: 139.4°C/W to: 263.7°C/W .	5
• Changed Junction-to-board thermal resistance value for DBV package from: 71.1°C/W to: 264.4°C/W	5
• Changed Junction-to-top characterization value for DBV package from: 45.2°C/W to: 195.6°C/W	5
• Changed Junction-to-board characterization value for DBV package from: 70.7°C/W to: 262.2°C/W	5

Changes from Revision Y (February 2017) to Revision Z (November 2017)	Page
• Changed values in the Thermal Information table to align with JEDEC standards	5
• Updated Feature Description to include more detailed information about specific device features.	9

-
- Added DPW layout example [12](#)
-

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74LVC1G06DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(C065, C06F, C06J, C06R, C06T) (C06H, C06P, C06S)
SN74LVC1G06DBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C065, C06F, C06J, C06R, C06T) (C06H, C06P, C06S)
SN74LVC1G06DBVR.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(C065, C06F, C06J, C06R, C06T) (C06H, C06P, C06S)
SN74LVC1G06DBVRE4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C06F
SN74LVC1G06DBVRG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C06F
SN74LVC1G06DBVRG4.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C06F
SN74LVC1G06DBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(C065, C06F, C06J, C06R) (C06H, C06P, C06S)
SN74LVC1G06DBVT.B	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	(C065, C06F, C06J, C06R) (C06H, C06P, C06S)
SN74LVC1G06DBVTG4	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C06F
SN74LVC1G06DBVTG4.B	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C06F
SN74LVC1G06DCKR	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(CT5, CTF, CTJ, CT K, CTR, CTT) (CTH, CTS)
SN74LVC1G06DCKR.A	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	(CT5, CTF, CTJ, CT K, CTR, CTT) (CTH, CTS)
SN74LVC1G06DCKR.B	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	(CT5, CTF, CTJ, CT K, CTR, CTT) (CTH, CTS)

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74LVC1G06DCKRE4	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CT5, CTF, CTK, CT R) (CTH, CTS)
SN74LVC1G06DCKRE4.B	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CT5, CTF, CTK, CT R) (CTH, CTS)
SN74LVC1G06DCKRG4	Active	Production	SC70 (DCK) 5	3000 null	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CT5
SN74LVC1G06DCKRG4.B	Active	Production	SC70 (DCK) 5	3000 null	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CT5
SN74LVC1G06DCKT	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(CT5, CTF, CTJ, CT K, CTR) (CTH, CTS)
SN74LVC1G06DCKT.B	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CT5, CTF, CTJ, CT K, CTR) (CTH, CTS)
SN74LVC1G06DCKTE4	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CT5, CTF, CTK, CT R) (CTH, CTS)
SN74LVC1G06DCKTE4.B	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CT5, CTF, CTK, CT R) (CTH, CTS)
SN74LVC1G06DCKTG4	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CT5, CTF, CTK, CT R) (CTH, CTS)
SN74LVC1G06DCKTG4.B	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(CT5, CTF, CTK, CT R) (CTH, CTS)
SN74LVC1G06DPWR	Active	Production	X2SON (DPW) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CO
SN74LVC1G06DPWR.B	Active	Production	X2SON (DPW) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CO
SN74LVC1G06DRLR	Active	Production	SOT-5X3 (DRL) 5	4000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	(CT7, CTR)
SN74LVC1G06DRLR.B	Active	Production	SOT-5X3 (DRL) 5	4000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	(CT7, CTR)
SN74LVC1G06DRYR	Active	Production	SON (DRY) 6	5000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	CT
SN74LVC1G06DRYR.B	Active	Production	SON (DRY) 6	5000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	CT
SN74LVC1G06DRYRG4	Active	Production	SON (DRY) 6	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CT
SN74LVC1G06DRYRG4.B	Active	Production	SON (DRY) 6	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CT
SN74LVC1G06DSFR	Active	Production	SON (DSF) 6	5000 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	CT

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74LVC1G06DSFR.B	Active	Production	SON (DSF) 6	5000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	CT
SN74LVC1G06DSFRG4	Active	Production	SON (DSF) 6	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CT
SN74LVC1G06DSFRG4.B	Active	Production	SON (DSF) 6	5000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CT
SN74LVC1G06YZPR	Active	Production	DSBGA (YZP) 5	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	CTN
SN74LVC1G06YZPR.B	Active	Production	DSBGA (YZP) 5	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	CTN
SN74LVC1G06YZVR	Active	Production	DSBGA (YZV) 4	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	CT N
SN74LVC1G06YZVR.B	Active	Production	DSBGA (YZV) 4	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	CT N

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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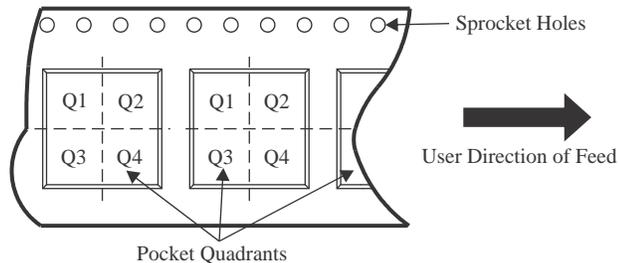
OTHER QUALIFIED VERSIONS OF SN74LVC1G06 :

- Automotive : [SN74LVC1G06-Q1](#)
- Enhanced Product : [SN74LVC1G06-EP](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G06DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74LVC1G06DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74LVC1G06DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G06DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74LVC1G06DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74LVC1G06DBVTG4	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G06DCKR	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
SN74LVC1G06DCKRE4	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G06DCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G06DCKT	SC70	DCK	5	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74LVC1G06DCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G06DCKT	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G06DCKTE4	SC70	DCK	5	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74LVC1G06DCKTE4	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G06DCKTE4	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G06DCKTG4	SC70	DCK	5	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G06DCKTG4	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G06DCKTG4	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G06DPWR	X2SON	DPW	5	3000	178.0	8.4	0.91	0.91	0.5	2.0	8.0	Q3
SN74LVC1G06DRLR	SOT-5X3	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74LVC1G06DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74LVC1G06DRYRG4	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74LVC1G06DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74LVC1G06DSFRG4	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74LVC1G06YZPR	DSBGA	YZP	5	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1
SN74LVC1G06YZVR	DSBGA	YZV	4	3000	178.0	9.2	1.0	1.0	0.63	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G06DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
SN74LVC1G06DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
SN74LVC1G06DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LVC1G06DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
SN74LVC1G06DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
SN74LVC1G06DBVTG4	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74LVC1G06DCKR	SC70	DCK	5	3000	208.0	191.0	35.0
SN74LVC1G06DCKRE4	SC70	DCK	5	3000	180.0	180.0	18.0
SN74LVC1G06DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G06DCKT	SC70	DCK	5	250	202.0	201.0	28.0
SN74LVC1G06DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G06DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G06DCKTE4	SC70	DCK	5	250	202.0	201.0	28.0
SN74LVC1G06DCKTE4	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G06DCKTE4	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G06DCKTG4	SC70	DCK	5	250	202.0	201.0	28.0
SN74LVC1G06DCKTG4	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G06DCKTG4	SC70	DCK	5	250	180.0	180.0	18.0

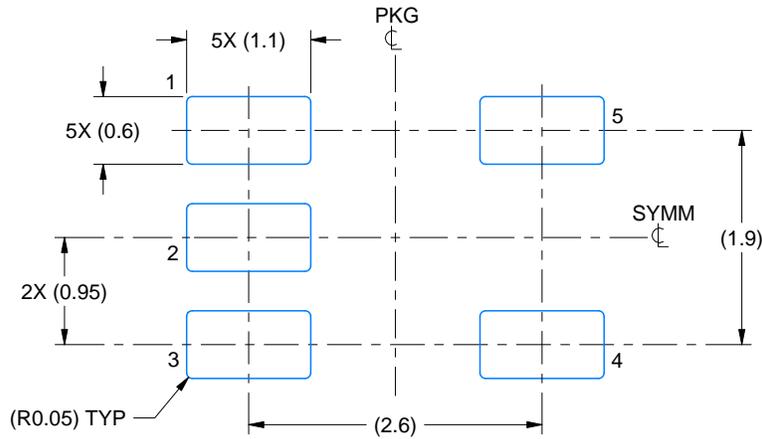
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G06DPWR	X2SON	DPW	5	3000	205.0	200.0	33.0
SN74LVC1G06DRLR	SOT-5X3	DRL	5	4000	202.0	201.0	28.0
SN74LVC1G06DRYR	SON	DRY	6	5000	184.0	184.0	19.0
SN74LVC1G06DRYRG4	SON	DRY	6	5000	184.0	184.0	19.0
SN74LVC1G06DSFR	SON	DSF	6	5000	184.0	184.0	19.0
SN74LVC1G06DSFRG4	SON	DSF	6	5000	184.0	184.0	19.0
SN74LVC1G06YZPR	DSBGA	YZP	5	3000	220.0	220.0	35.0
SN74LVC1G06YZVR	DSBGA	YZV	4	3000	220.0	220.0	35.0

EXAMPLE BOARD LAYOUT

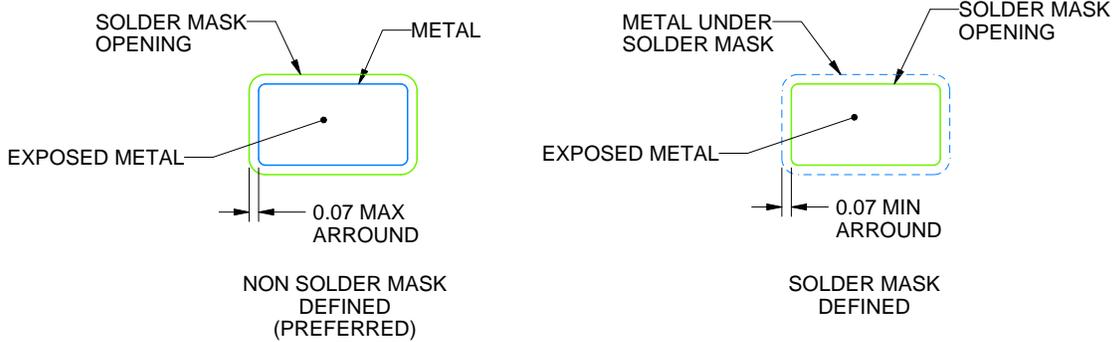
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

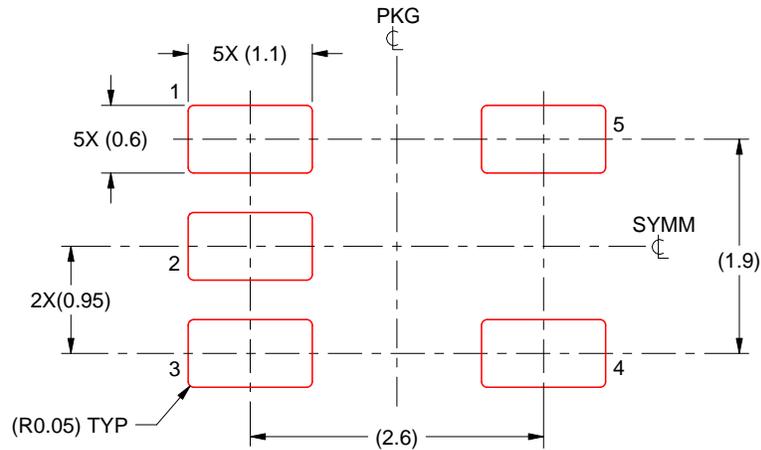
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

DRY 6

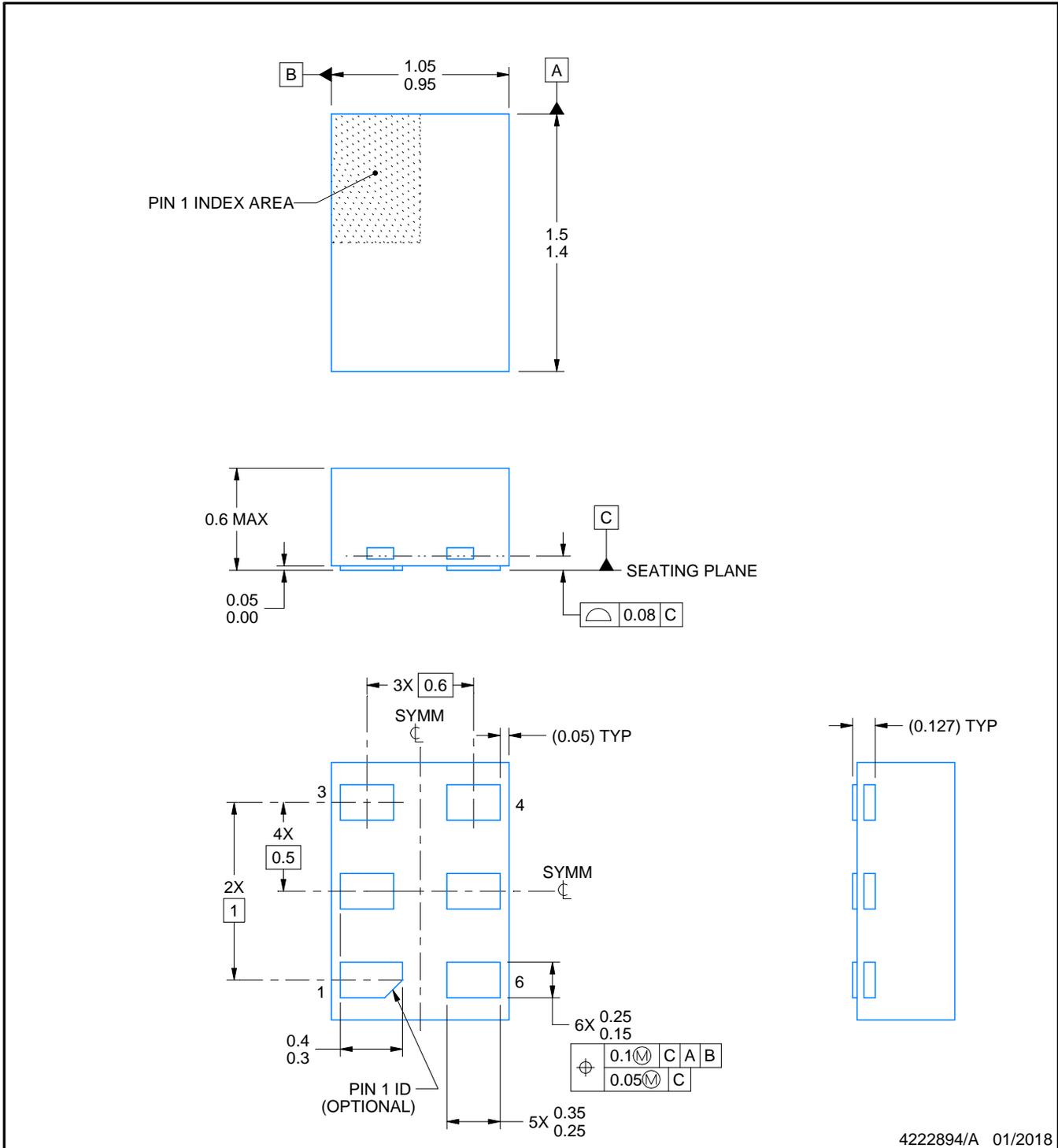
USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4207181/G



NOTES:

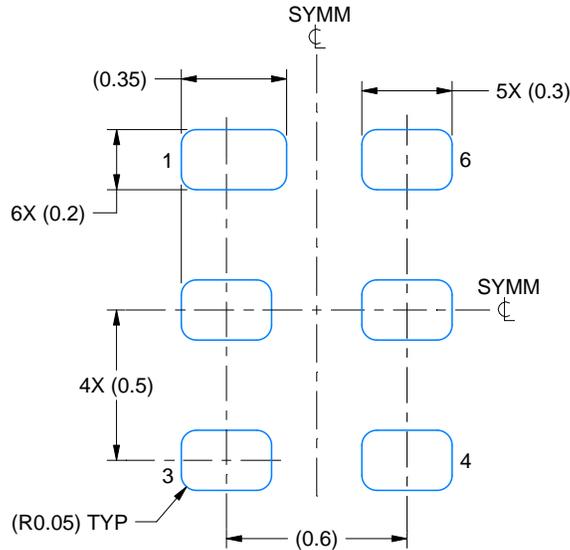
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

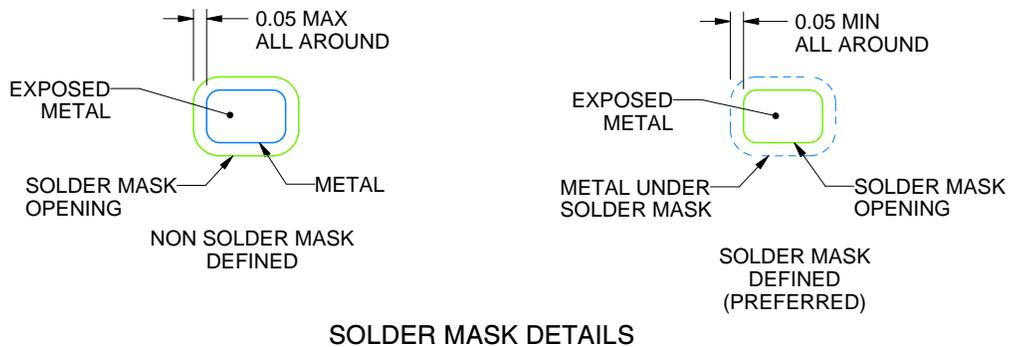
DRY0006A

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
1:1 RATIO WITH PKG SOLDER PADS
EXPOSED METAL SHOWN
SCALE:40X



SOLDER MASK DETAILS

4222894/A 01/2018

NOTES: (continued)

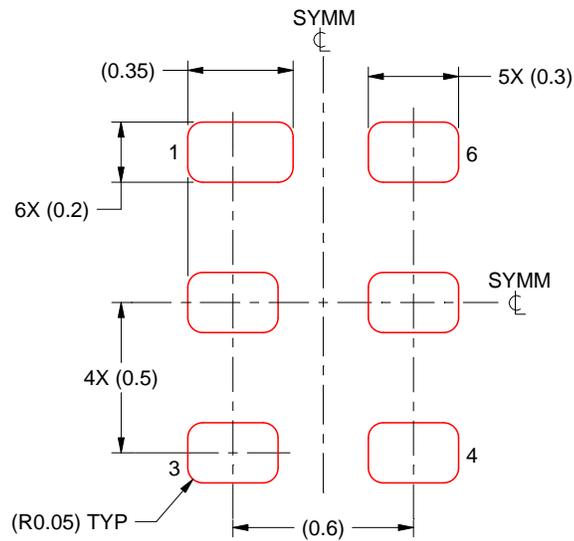
3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/sluea271).

EXAMPLE STENCIL DESIGN

DRY0006A

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.075 - 0.1 mm THICK STENCIL
SCALE:40X

4222894/A 01/2018

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

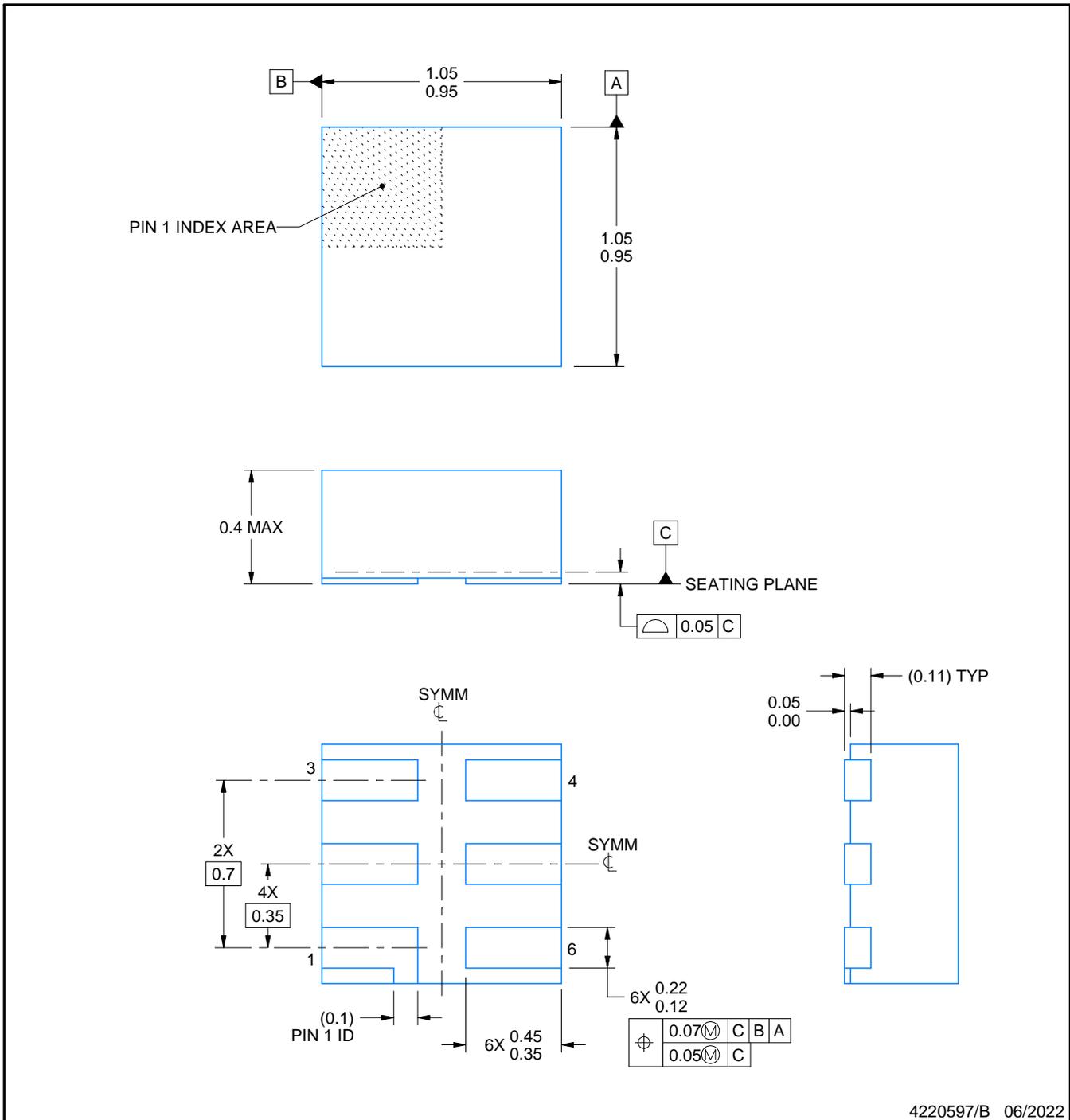


DSF0006A

PACKAGE OUTLINE

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



4220597/B 06/2022

NOTES:

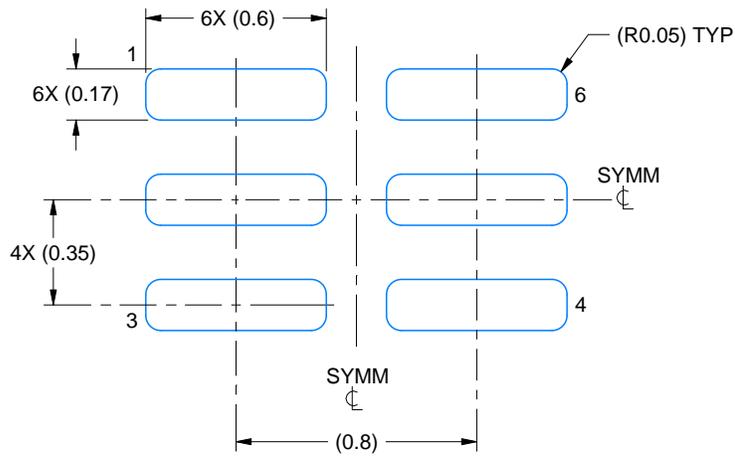
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration MO-287, variation X2AAF.

EXAMPLE BOARD LAYOUT

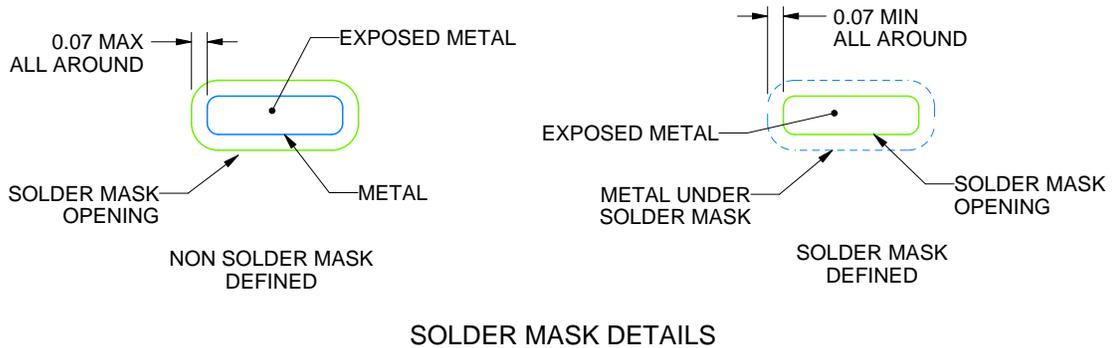
DSF0006A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:40X



SOLDER MASK DETAILS

4220597/B 06/2022

NOTES: (continued)

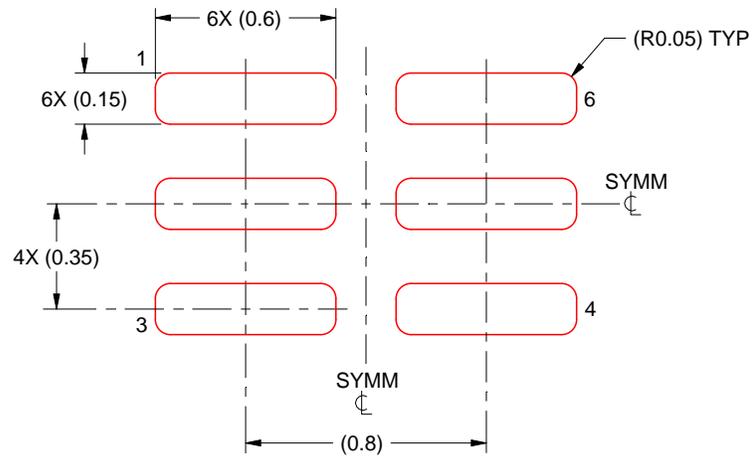
4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

EXAMPLE STENCIL DESIGN

DSF0006A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

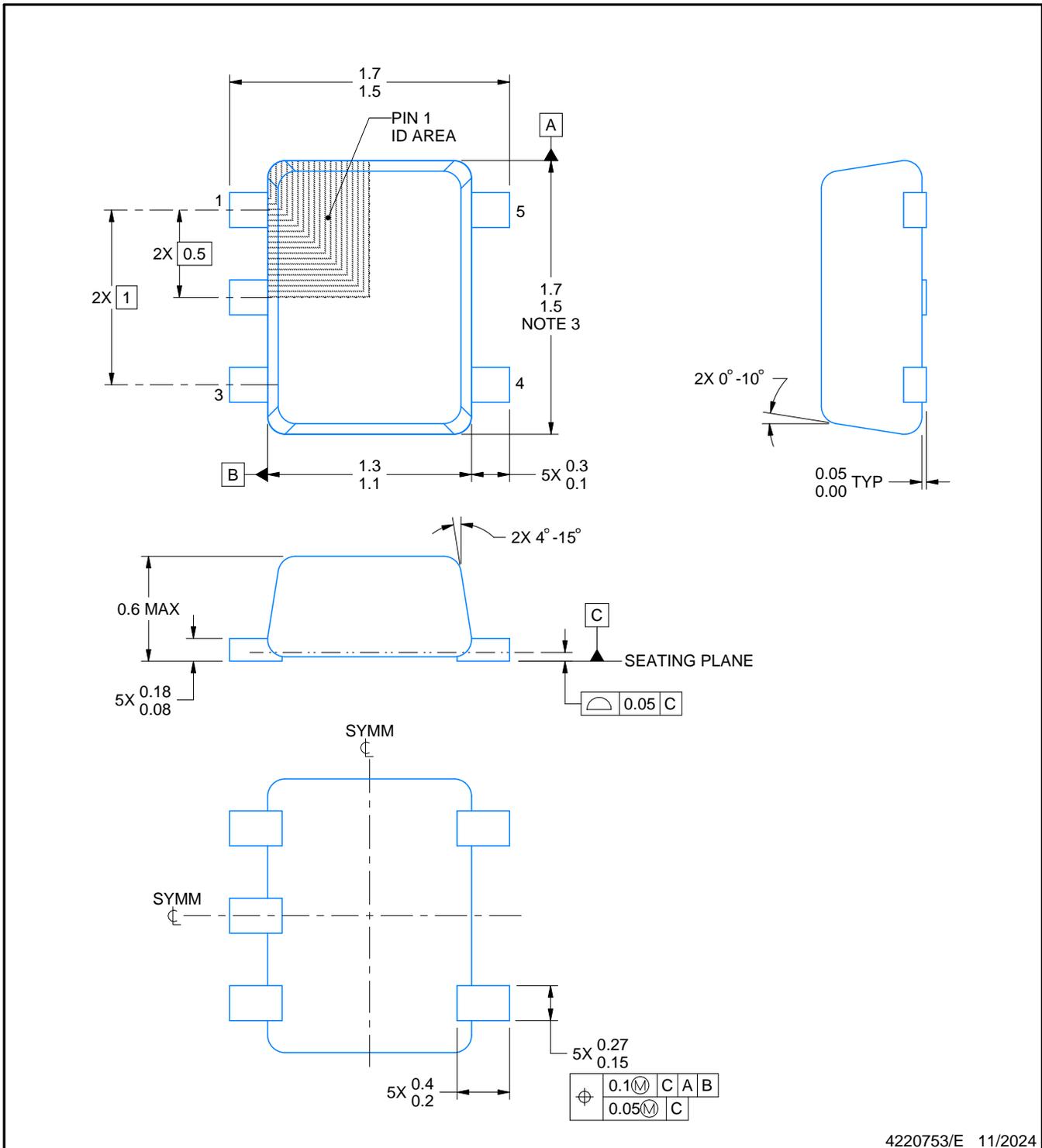
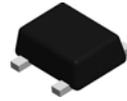


SOLDER PASTE EXAMPLE
BASED ON 0.09 mm THICK STENCIL

PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:40X

4220597/B 06/2022

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



NOTES:

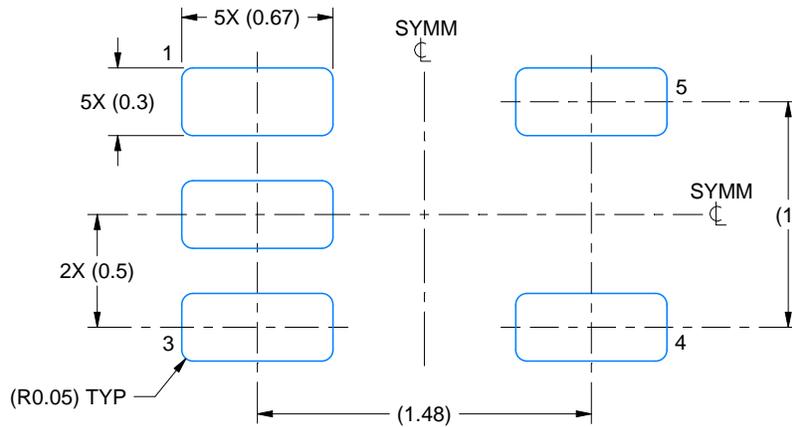
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-293 Variation UAAD-1

EXAMPLE BOARD LAYOUT

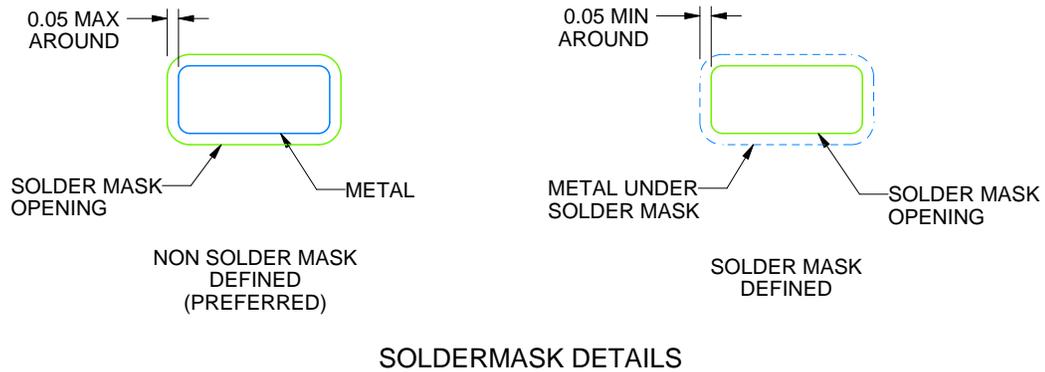
DRL0005A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE
SCALE:30X



SOLDERMASK DETAILS

4220753/E 11/2024

NOTES: (continued)

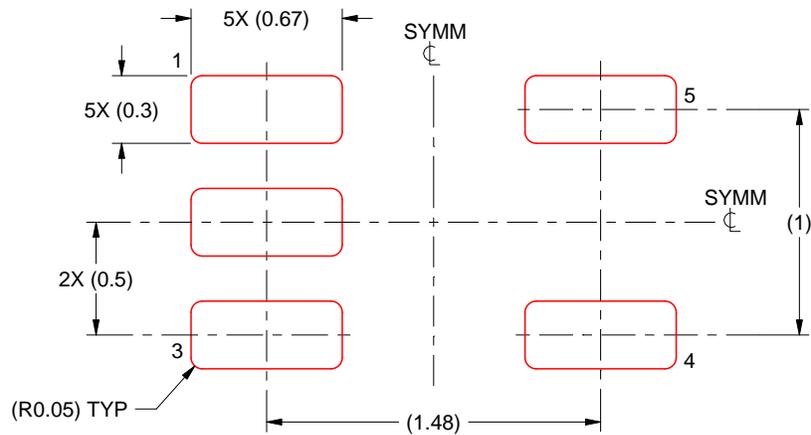
- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DRL0005A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:30X

4220753/E 11/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

DPW 5

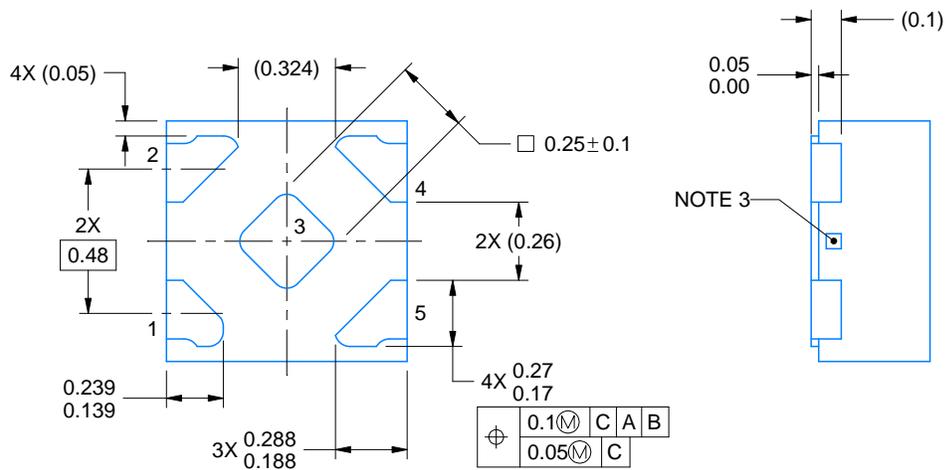
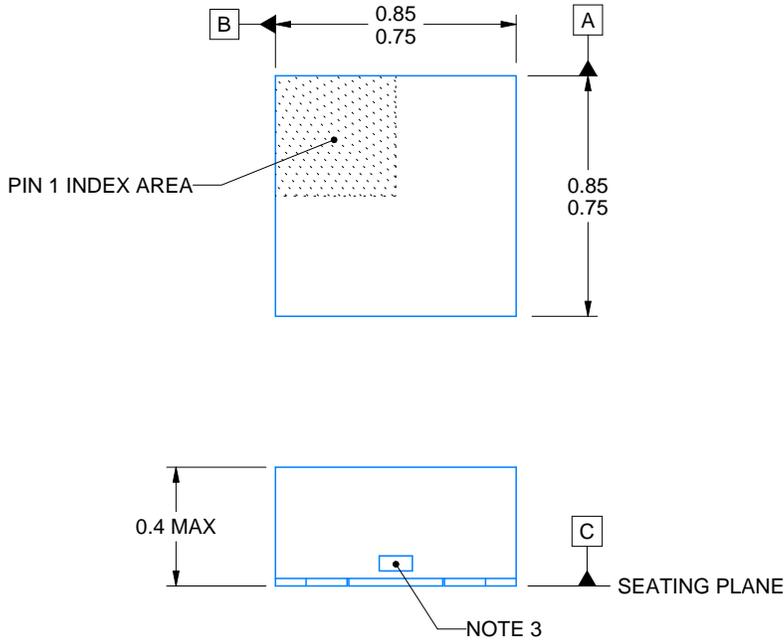
X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4211218-3/D



4223102/D 03/2022

NOTES:

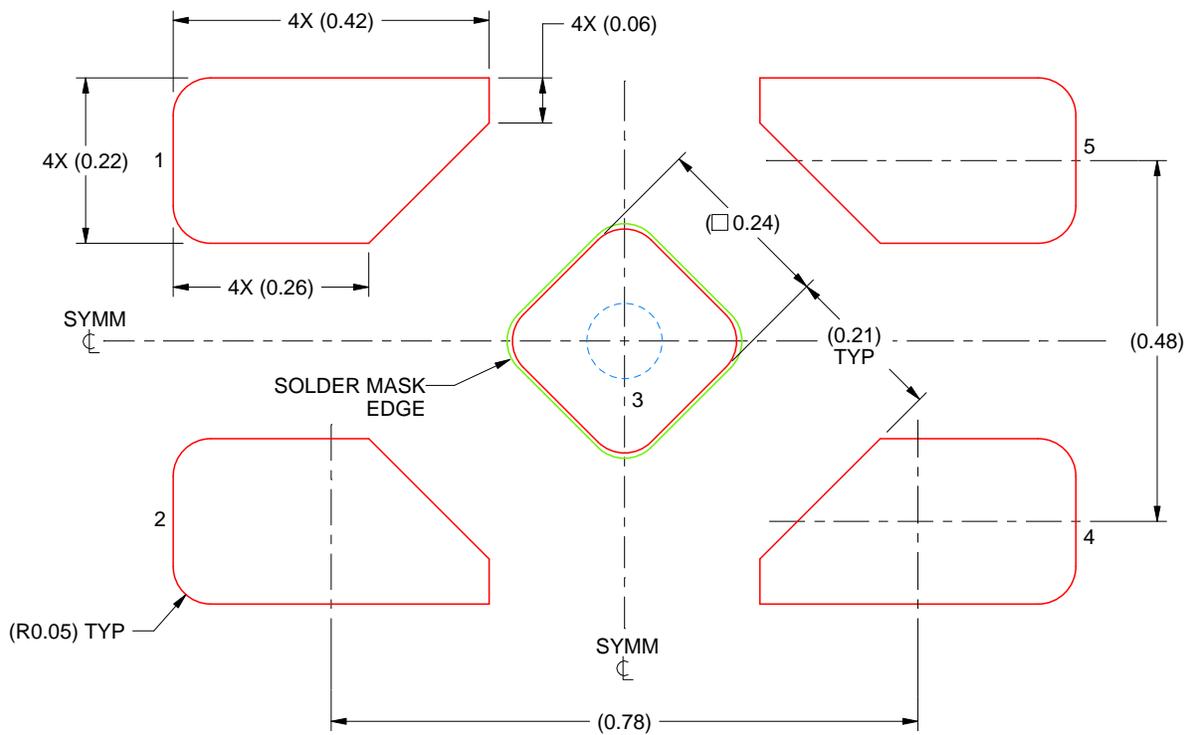
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The size and shape of this feature may vary.

EXAMPLE STENCIL DESIGN

DPW0005A

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL

EXPOSED PAD 3
92% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:100X

4223102/D 03/2022

NOTES: (continued)

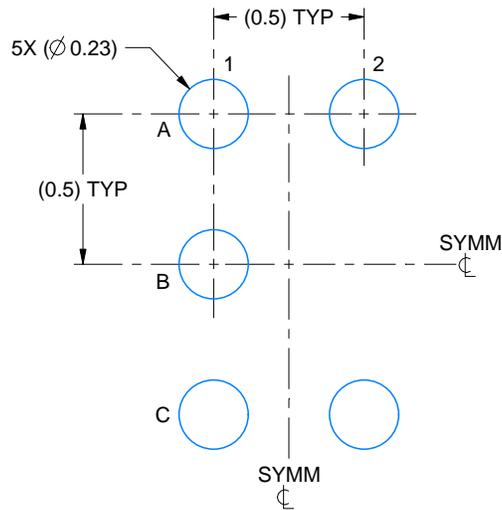
5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

EXAMPLE BOARD LAYOUT

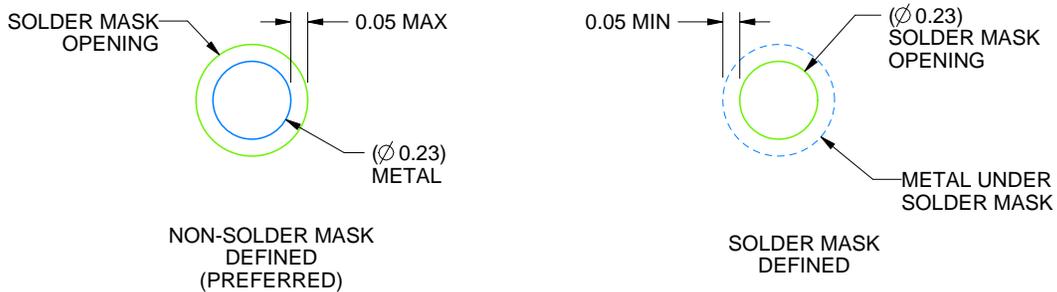
YZP0005

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE
SCALE:40X



SOLDER MASK DETAILS
NOT TO SCALE

4219492/A 05/2017

NOTES: (continued)

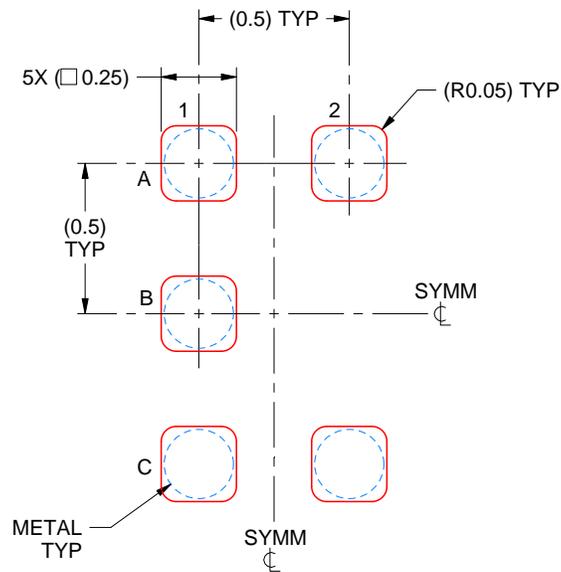
3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).

EXAMPLE STENCIL DESIGN

YZP0005

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:40X

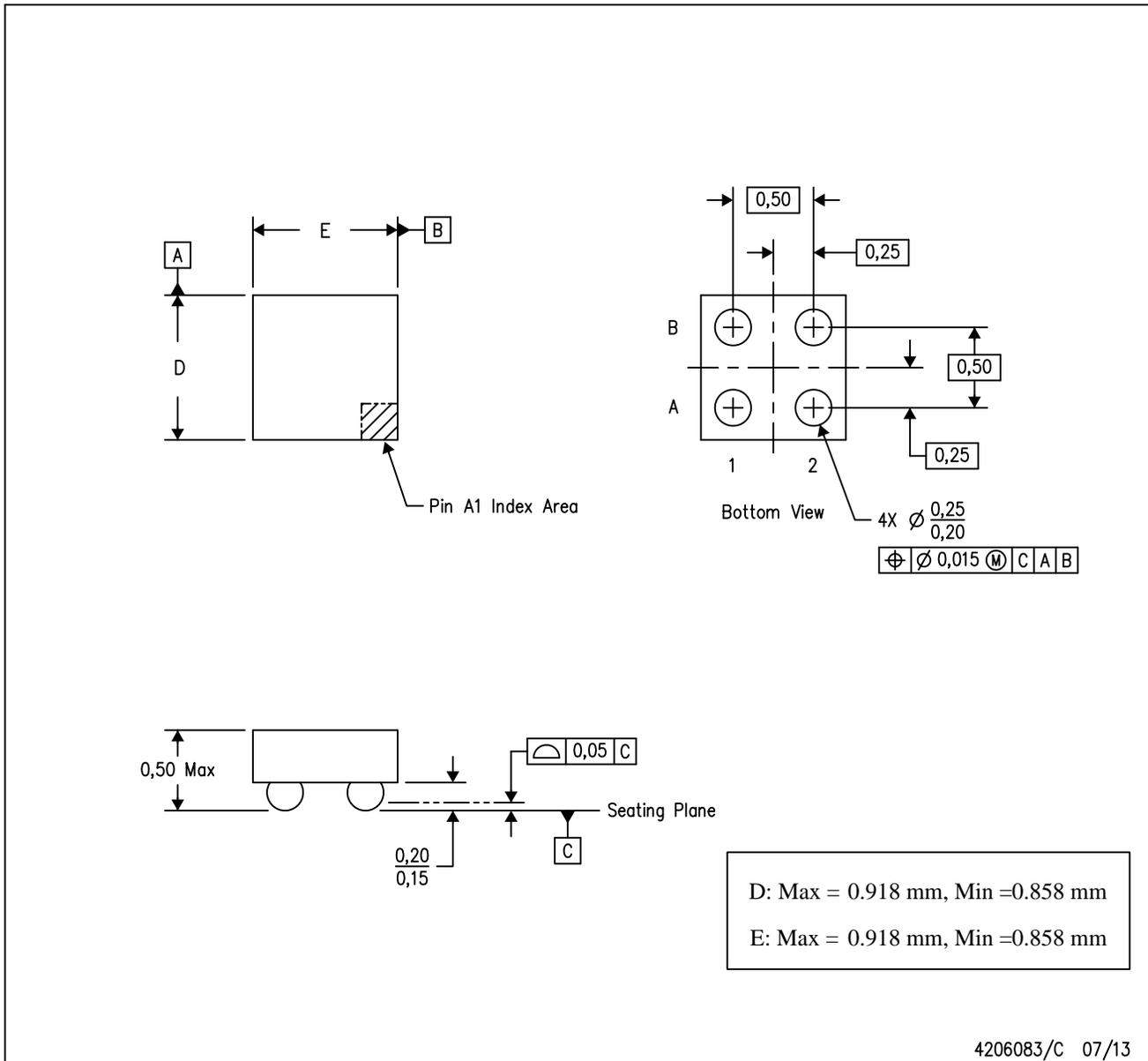
4219492/A 05/2017

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

YZV (S-XBGA-N4)

DIE-SIZE BALL GRID ARRAY



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. NanoFree™ package configuration.

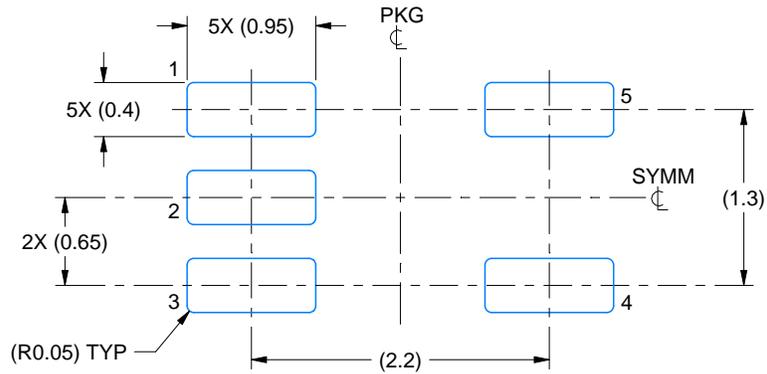
NanoFree is a trademark of Texas Instruments.

EXAMPLE BOARD LAYOUT

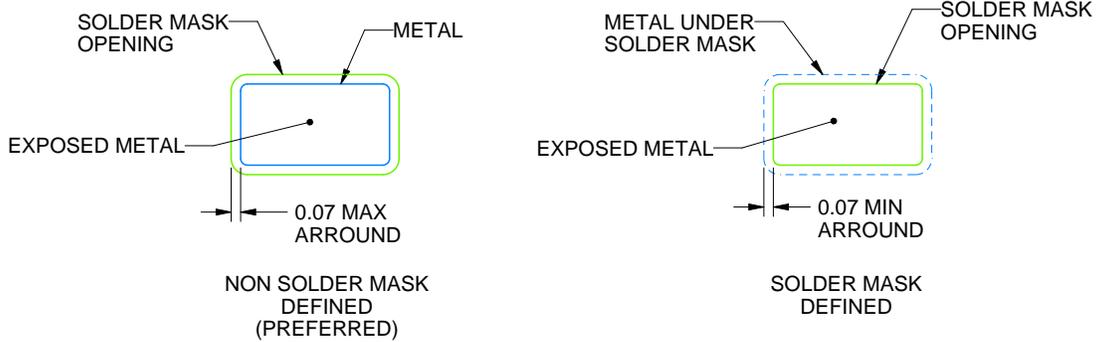
DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:18X



SOLDER MASK DETAILS

4214834/G 11/2024

NOTES: (continued)

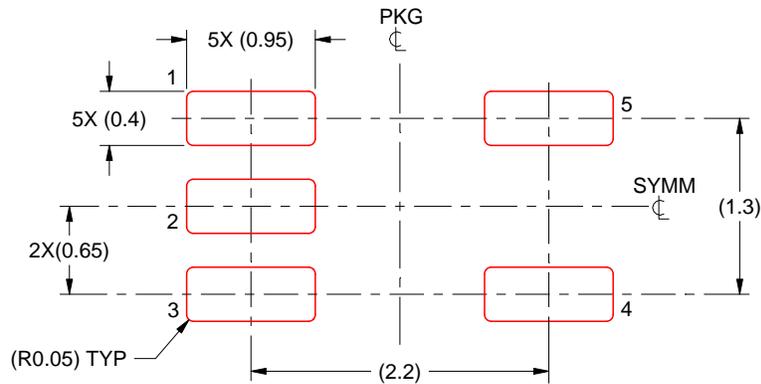
- 7. Publication IPC-7351 may have alternate designs.
- 8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE: 18X

4214834/G 11/2024

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.

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